

## Description

The TELUX™ series is a clear, non diffused LED for applications where supreme luminous flux is required. It is designed in an industry standard 7.62 mm square package utilizing highly developed with super bright, AlInGaP, OMA technology.

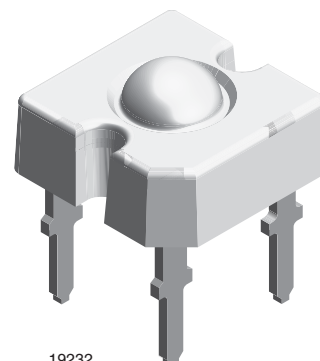
The supreme heat dissipation of TELUX™ allows applications at high ambient temperatures.

All packing units are binned for luminous flux, forward voltage and color to achieve the most homogenous light appearance in application.

SAE and ECE color requirements for automobile

application are available for color red.

ESD resistivity 2 kV (HBM) according to MIL STD 883D, method 3015.7.



19232

## Applications

Exterior lighting

Tail-, Stop - and Turn Signals of motor vehicles

Replaces small incandescent lamps

Traffic signals and signs

## Features

- Utilizing one of the world's brightest (AS) AlInGaP technologies (OMA)
- High luminous flux
- Supreme heat dissipation:  $R_{thJP}$  is 90 K/W
- High operating temperature:  
 $T_{amb} = -40$  to  $+110$  °C
- Meets SAE and ECE color requirements for the automobile industry for color red
- Packed in tubes for automatic insertion
- Luminous flux, forward voltage and color categorized for each tube
- Small mechanical tolerances allow precise usage of external reflectors or lightguides
- Lead (Pb)-free component
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC



## Parts Table

Part	Color, Luminous Intensity	Angle of Half Intensity ( $\pm\phi$ )	Technology
TLWR9620	Red, $\phi_V > 3000$ mIm	30 °	AlInGaP on Si
TLWR9621	Red, $\phi_V > 3500$ mIm	30 °	AlInGaP on Si
TLWR9622	Red, $\phi_V > 4000$ mIm	30 °	AlInGaP on Si

## Absolute Maximum Ratings

$T_{amb} = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified

TLWR962.

Parameter	Test condition	Symbol	Value	Unit
Reverse voltage	$I_R = 100\text{ }\mu\text{A}$	$V_R$	10	V
DC Forward current	$T_{amb} \leq 85\text{ }^{\circ}\text{C}$	$I_F$	70	mA
Surge forward current	$t_p \leq 10\text{ }\mu\text{s}$	$I_{FSM}$	0.1	A
Power dissipation		$P_V$	212	mW
Junction temperature		$T_j$	125	$^{\circ}\text{C}$
Operating temperature range		$T_{amb}$	- 40 to + 110	$^{\circ}\text{C}$
Storage temperature range		$T_{stg}$	- 40 to + 110	$^{\circ}\text{C}$
Soldering temperature	$t \leq 5\text{ s}$ , 1.5 mm from body preheat temperature 100 $^{\circ}\text{C}$ / 30 sec.	$T_{sd}$	260	$^{\circ}\text{C}$
Thermal resistance junction/ ambient	with cathode heatsink of 70 mm <sup>2</sup>	$R_{thJA}$	200	K/W

## Optical and Electrical Characteristics

$T_{amb} = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified

### Red

TLWR962.

Parameter	Test condition	Part	Symbol	Min	Typ.	Max	Unit
Total flux	$I_F = 70\text{ mA}$ , $R_{thJA} = 200\text{ }^{\circ}\text{K/W}$	TLWR9620	$\phi_V$	3000	3700		mlm
		TLWR9621	$\phi_V$	3500	4200		mlm
		TLWR9622	$\phi_V$	4000	5000		mlm
Luminous intensity/Total flux	$I_F = 70\text{ mA}$ , $R_{thJA} = 200\text{ }^{\circ}\text{K/W}$		$I_V/\phi_V$		0.8		mcd/ mlm
Dominant wavelength	$I_F = 70\text{ mA}$ , $R_{thJA} = 200\text{ }^{\circ}\text{K/W}$		$\lambda_d$	611	615	634	nm
Peak wavelength	$I_F = 70\text{ mA}$ , $R_{thJA} = 200\text{ }^{\circ}\text{K/W}$		$\lambda_p$		624		nm
Angle of half intensity	$I_F = 70\text{ mA}$ , $R_{thJA} = 200\text{ }^{\circ}\text{K/W}$		$\varphi$		$\pm 30$		deg
Total included angle	90 % of Total Flux Captured		$\varphi_{0.9V}$		75		deg
Forward voltage	$I_F = 70\text{ mA}$ , $R_{thJA} = 200\text{ }^{\circ}\text{K/W}$		$V_F$	1.83	2.5	3.03	V
Reverse voltage			$V_R$	10	20		V
Temperature coefficient $< \lambda_d$	$I_F = 70\text{ mA}$		$TC\lambda_d$		17		nm/K
Temperature coefficient $V_F$	$I_F = 70\text{ mA}$ , $T > - 25\text{ }^{\circ}\text{C}$		$TCV_F$		- 2.0		mV/K

## Forward Voltage Classification

Group	Forward Voltage (V)	
	min	max
Y	1.83	2.07
Z	1.95	2.19
0	2.07	2.31
1	2.19	2.43
2	2.31	2.55
3	2.43	2.67
4	2.55	2.79
5	2.67	2.91
6	2.79	3.03

## Color Classification

Group	Dominant Wavelength (nm)	
	min	max
1	611	618
2	614	622
3	616	634

## Luminous Flux Classification

Group	Luminous Intensity (mIm)	
	min	max
F	3000	4200
G	3500	4800
H	4000	6100
I	5000	7300
K	6000	9700

## Typical Characteristics (Tamb = 25 °C unless otherwise specified)

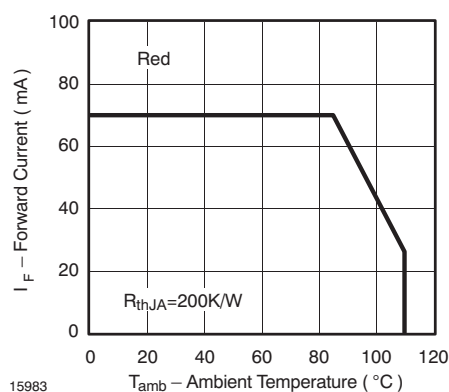


Figure 1. Forward Current vs. Ambient Temperature

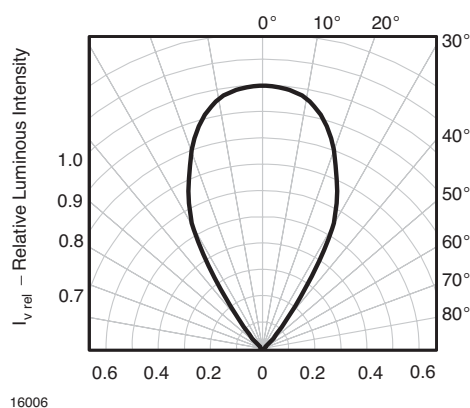


Figure 3. Rel. Luminous Intensity vs. Angular Displacement for 60 ° emission angle

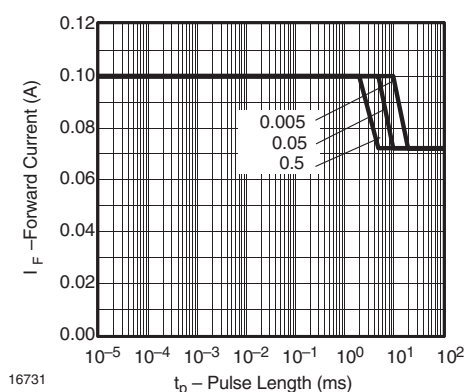


Figure 2. Forward Current vs. Pulse Length

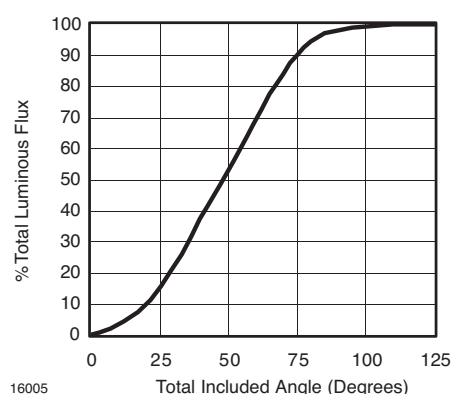


Figure 4. Percentage Total Luminous Flux vs. Total Included Angle for 60 ° emission angle

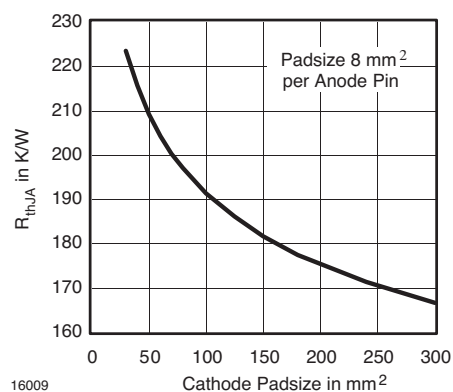
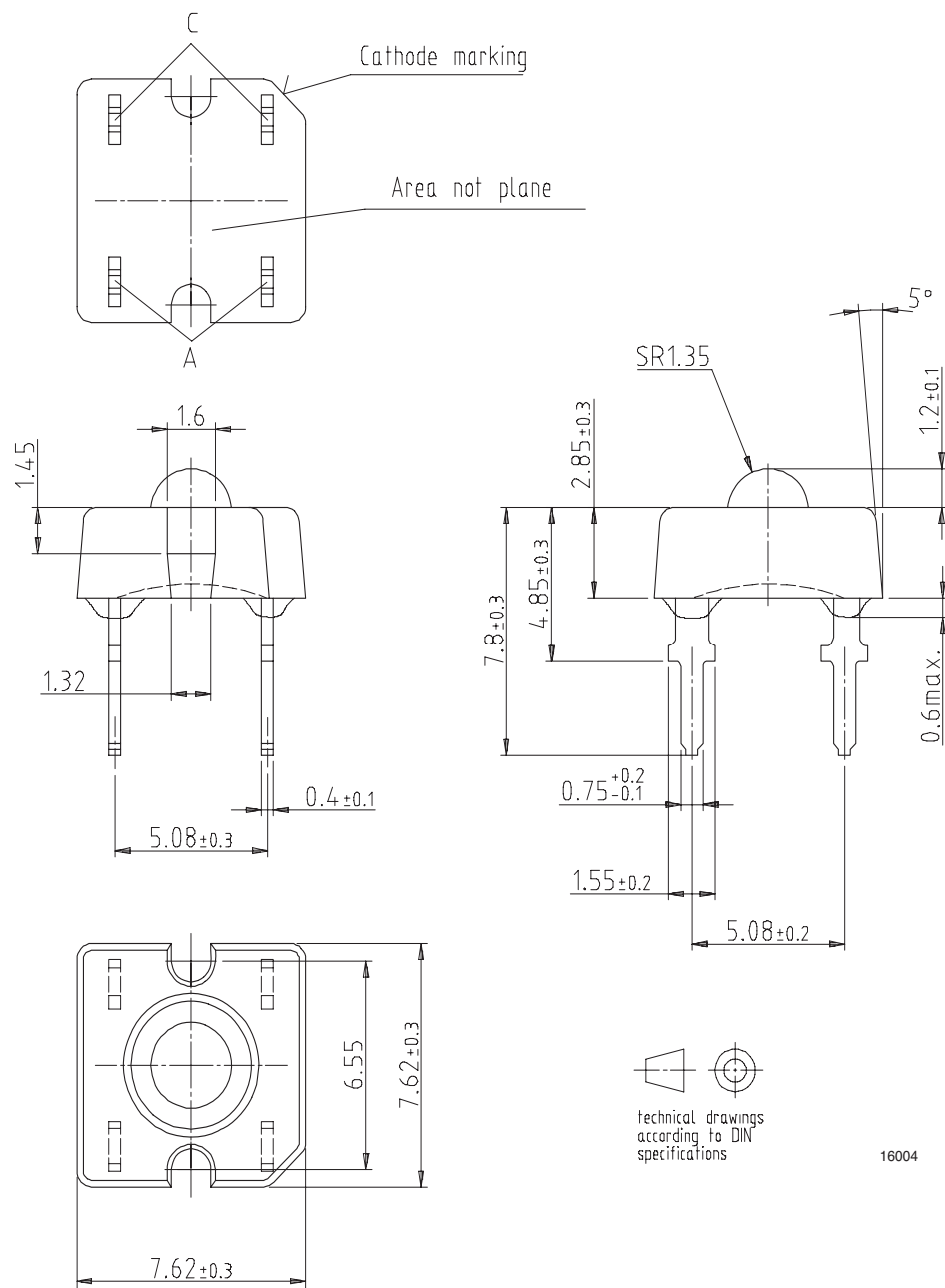


Figure 5. Thermal Resistance Junction Ambient vs. Cathode Padsize

## Package Dimensions in mm





## Ozone Depleting Substances Policy Statement

It is the policy of Vishay Semiconductor GmbH to

1. Meet all present and future national and international statutory requirements.
2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design  
and may do so without further notice.

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay Semiconductors products for any unintended or unauthorized application, the buyer shall indemnify Vishay Semiconductors against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

Vishay Semiconductor GmbH, P.O.B. 3535, D-74025 Heilbronn, Germany



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